

## N-Channel Super Junction Power MOSFET $\, III \,$

### **General Description**

The series of devices use advanced trench gate super junction technology and design to provide excellent R<sub>DS(ON)</sub> with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

#### Features

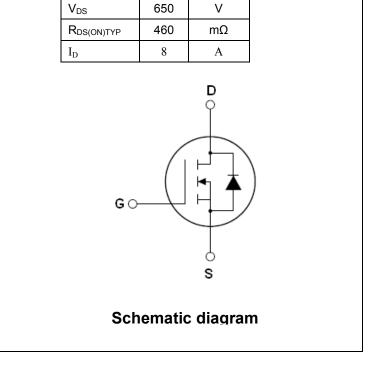
- •New technology for high voltage device
- •Low on-resistance and low conduction losses
- ●Small package
- ●Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ●ROHS compliant

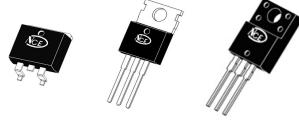
### Application

- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)

Package Marking And Ordering Information					
Device	Device Package	Marking			
NCE65T540D	TO-263	NCE65T540D			
NCE65T540	TO-220	NCE65T540			
NCE65T540F	TO-220F	NCE65T540F			

### Table 1. Absolute Maximum Ratings (T<sub>c</sub>=25℃)





TO-263

TO-220

TO-220F

Parameter	Symbol	NCE65T540D NCE65T540	NCE65T540F	Unit		
Drain-Source Voltage (VGs=0V)	Vds	650		V		
Gate-Source Voltage (VDs=0V) AC (f>1 Hz)	Vgs	±30		V		
Continuous Drain Current at Tc=25°C	I <sub>D (DC)</sub>	8	8*	А		
Continuous Drain Current at Tc=100°C	I <sub>D (DC)</sub>	5.2	5.2*	А		
Pulsed drain current (Note 1)	I <sub>DM (pluse)</sub>	32	32*	А		
Maximum Power Dissipation(Tc=25°C)	PD	69	31.6	W		
Derate above 25°C		0.55	0.25	W/°C		
Single pulse avalanche energy (Note 2)	Eas	156		mJ		
Avalanche current <sup>(Note 1)</sup>	I <sub>AR</sub>	1.7		А		
Repetitive Avalanche energy , $t_{\text{AR}}$ limited by $T_{\text{jmax}}$ (Note 1)	E <sub>AR</sub>	0.3		mJ		



## NCE65T540D,NCE65T540,NCE65T540F

Parameter	Symbol	NCE65T540D NCE65T540	NCE65T540F	Unit
Drain Source voltage slope, $V_{DS} \leq 480 V$ ,	dv/dt	50		V/ns
Reverse diode dv/dt, $V_{DS} \leqslant 480 V, I_{SD} < I_D$	dv/dt	1	5	V/ns
Operating Junction and Storage Temperature Range	$T_J,T_STG$	-55	+150	°C

\* limited by maximum junction temperature

#### Table 2. Thermal Characteristic

Symbol	NCE65T540D NCE65T540	NCE65T540F	Unit
R <sub>thJC</sub>	1.81	3.95	°C /W
R <sub>thJA</sub>	62	80	°C /W
	R <sub>thJC</sub>	Symbol NCE65T540   R <sub>thJC</sub> 1.81	Symbol NCE65T540   R <sub>thJC</sub> 1.81 3.95

## Table 3. Electrical Characteristics (TA=25 $^\circ\!\!\mathrm{C}$ unless otherwise noted)

Parameter	Symbol	Symbol Condition		Тур	Мах	Unit
On/off states			•			
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	650			V
Zero Gate Voltage Drain Current(Tc=25℃)	I <sub>DSS</sub>	V <sub>DS</sub> =650V,V <sub>GS</sub> =0V			1	μA
Zero Gate Voltage Drain Current(Tc=125℃)	I <sub>DSS</sub>	V <sub>DS</sub> =650V,V <sub>GS</sub> =0V			100	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V,V <sub>DS</sub> =0V			±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	3		4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =4A		460	540	mΩ
Dynamic Characteristics		·				
Input Capacitance	Clss			590		pF
Output Capacitance	Coss	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V, F=1.0MHz		37		pF
Reverse Transfer Capacitance	Crss			0.9		pF
Total Gate Charge	Qg	)/ _400)// _04		14.6	22	nC
Gate-Source Charge	Q <sub>gs</sub>	V <sub>DS</sub> =480V,I <sub>D</sub> =8A, V <sub>GS</sub> =10V		4		nC
Gate-Drain Charge	Q <sub>gd</sub>	V <sub>GS</sub> =10V		6.7		nC
Switching times		·				
Turn-on Delay Time	t <sub>d(on)</sub>			8		nS
Turn-on Rise Time	tr	V <sub>DD</sub> =380V,I <sub>D</sub> =4A,		6		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> =4.7Ω,V <sub>GS</sub> =10V		59	75	nS
Turn-Off Fall Time	t <sub>f</sub>			10	15	nS
Source- Drain Diode Characteristics		·				
Source-drain current(Body Diode)	I <sub>SD</sub>	T <sub>C</sub> =25°C			8	А
Pulsed Source-drain current(Body Diode)	I <sub>SDM</sub>	1 <sub>C</sub> =25 C			32	А
Forward On Voltage	V <sub>SD</sub>	Tj=25°C,I <sub>SD</sub> =8A,V <sub>GS</sub> =0V		0.9	1.2	V
Reverse Recovery Time	t <sub>rr</sub>	Tj=25°C,I <sub>F</sub> =4A,di/dt=100A/µs		230		nS
Reverse Recovery Charge	Qrr			1.2		uC
Peak Reverse Recovery Current	I <sub>rrm</sub>			10.5		А

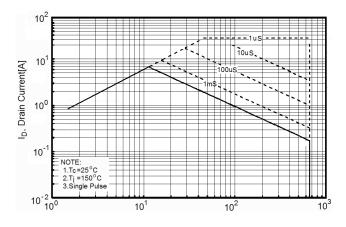
Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25°C,VDD=50V,VG=10V, R\_G=25\Omega



## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

#### Figure1. Safe operating area



#### Figure3. Source-Drain Diode Forward Voltage

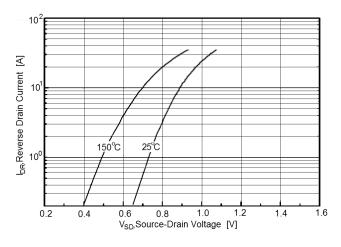
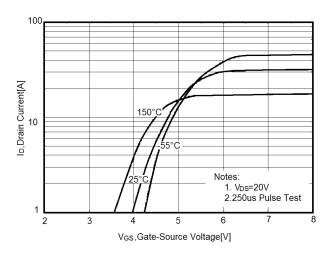
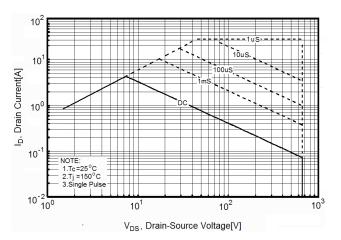


Figure 5. Transfer characteristics



#### Figure 2. Safe operating area for TO-220F



#### Figure4. Output characteristics

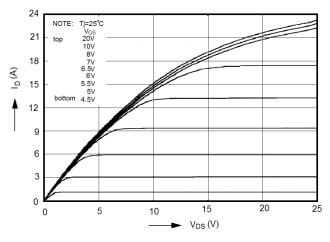
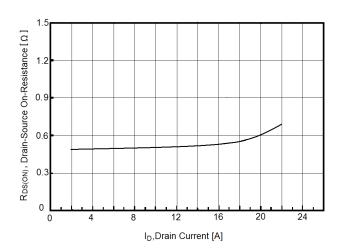


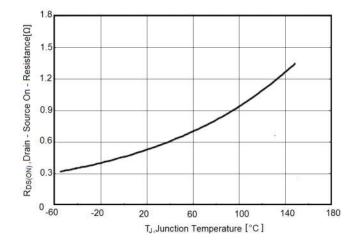
Figure6. Static drain-source on resistance





#### Figure7. R<sub>DS(ON)</sub> vs Junction Temperature

#### Figure8. BV<sub>DSS</sub> vs Junction Temperature



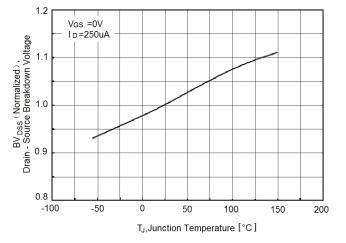


Figure9. Maximum I<sub>D</sub> vs Junction Temperature

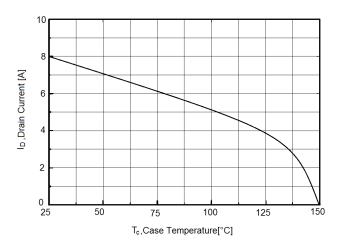


Figure11. Gate charge waveforms



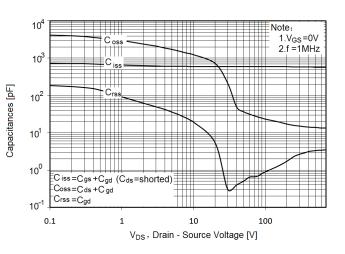
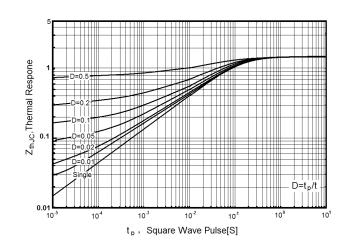
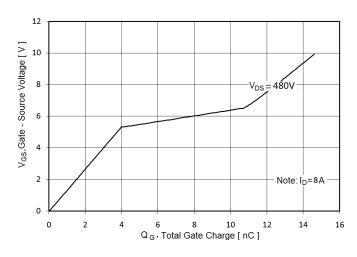


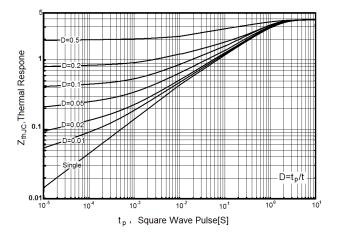
Figure12. Transient Thermal Impedance







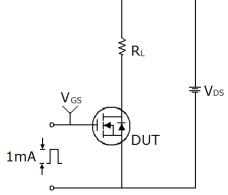
### Figure13. Transient Thermal Impedance for TO-220F

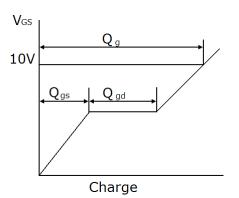




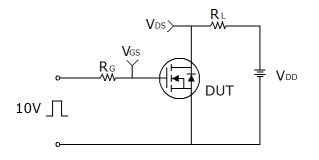
## Test circuit

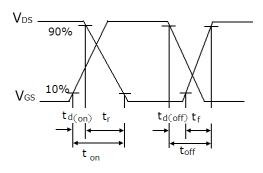
1) Gate charge test circuit & Waveform



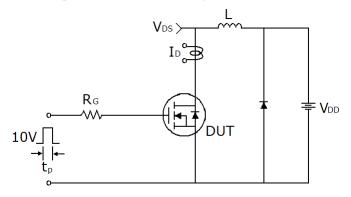


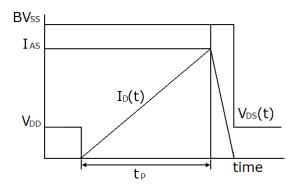
2) Switch Time Test Circuit:





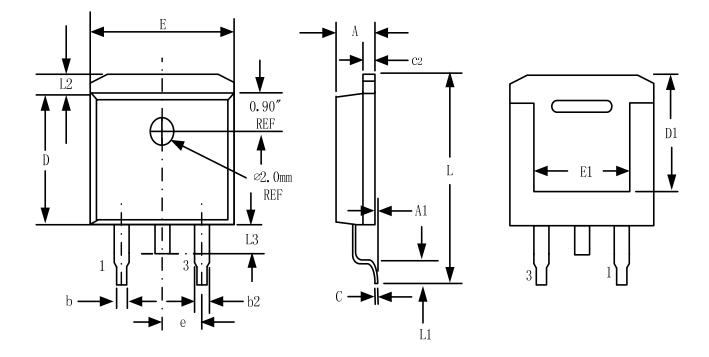
3) Unclamped Inductive Switching Test Circuit & Waveforms







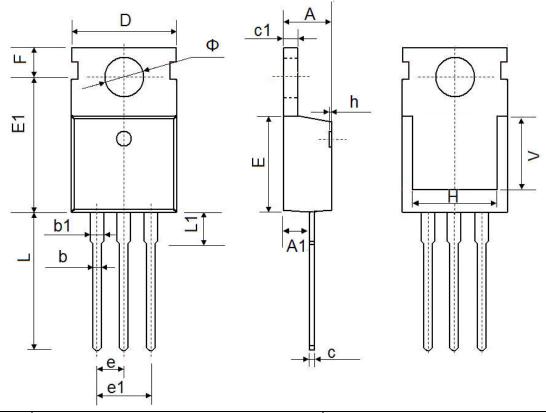
# **TO-263-3L Package Information**



Sumbal	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.32	4.57	0.170	0.180	
A1	-	0.25		0.010	
b	0.71	0.94	0.028	0.037	
b2	1.15	1.40	0.045	0.055	
с	0.46	0.61	0.018	0.024	
c2	1.22	1.40	0.048	0.055	
D	8.89	9.40	0.350	0.370	
D1	8.01	8.23	0.315	0.324	
E	10.04	10.28	0.395	0.405	
E1	7.88	8.08	0.310	0.318	
е	2.54	2.54 BSC		BSC	
L	14.73	15.75	0.580	0.620	
L1	2.29	2.79	0.090	0.110	
L2	1.15	1.39	0.045	0.055	
L3	1.27	1.77	0.050	0.070	



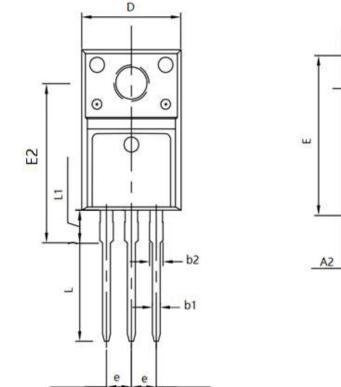
# **TO-220-3L-C Package Information**

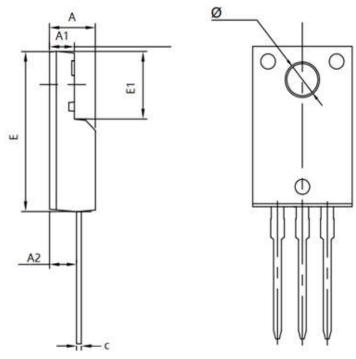


Sumah al	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540 TYP.		0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500 REF.		0.295	REF.	
Ф	3.400	3.800	0.134	0.150	



# **TO-220F Package Information**





Symbol	Dimensions	In Millimeters	Dimensions In Inches		
	Min.	Max.	Min.	Max.	
A	4.500	4.900	0.177	0.193	
A1	2.340	2.740	0.092	0.108	
A2	2.560	2.960	0.101	0.117	
b1	0.700	0.900	0.028	0.035	
b2	1.180	1.580	0.046	0.062	
с	0.400	0.600	0.016	0.024	
D	9.960	10.360	0.392	0.408	
E	15.670	15.970	0.617	0.629	
E1	6.500	6.900	0.256	0.272	
E2	15.500	16.100	0.610	0.634	
e	2.540	2.540 TYP		) TYP	
Φ	3.080	3.280	0.121	0.129	
L	12.640	13.240	0.498	0.521	
L1	3.030	3.430	0.119	0.135	



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